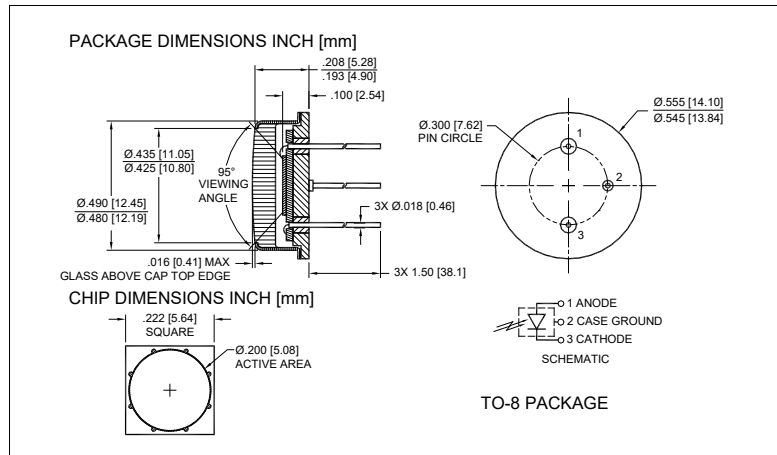
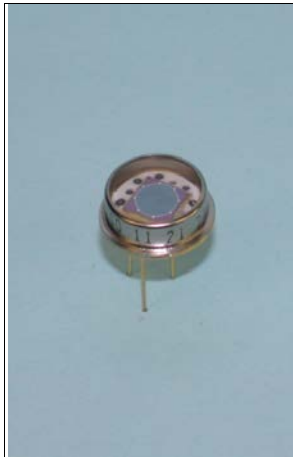


Red Enhanced Silicon Photodiode

SD200-11-21-241

Precision – Control – Results



DESCRIPTION

The **SD 200-11-21-241** is a general purpose silicon PIN photodiode, red enhanced, packaged in a leaded hermetic TO-8 metal package.

FEATURES

- Low Noise
- Red Enhanced
- High Shunt Resistance
- High Response

RELIABILITY

Contact Luna for recommendations on specific test conditions and procedures.

APPLICATIONS

- Instrumentation
- Industrial
- Medical



ABSOLUTE MAXIMUM RATINGS

SYMBOL	MIN		MAX	UNITS	
Reverse Voltage	-	-	75	V	$T_a = 23^\circ\text{C}$ UNLESS OTHERWISE NOTED
Storage Temperature	-55	to	+150	$^\circ\text{C}$	-
Operating Temperature	-40	to	+125	$^\circ\text{C}$	-
Soldering Temperature	-	-	+240	$^\circ\text{C}$	-

* 1/16 inch from case for 3 seconds max.

Information in this technical datasheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.

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Red Enhanced Silicon Photodiode
SD200-11-21-241

Precision – Control – Results

OPTO-ELECTRICAL PARAMETERS

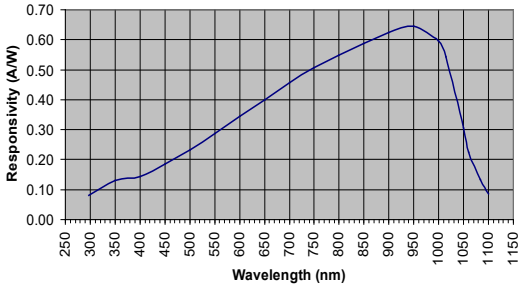
T_a = 23°C UNLESS NOTED OTHERWISE

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Dark Current	V _R = 5V	-	6.5	26.0	nA
Shunt Resistance	V _R = 10 mV	70	-	-	MΩ
Junction Capacitance	V _R = 0V, f = 1 MHz	-	345	-	pF
	V _R = 10V, f = 1 MHz	-	71	-	
Spectral Application Range	Spot Scan	350	-	1100	nm
Responsivity	λ = 633 nm, V _R = 0V	0.32	0.36	-	A/W
	λ = 900nm, V _R = 0V	0.50	0.55	-	
Breakdown Voltage	I = 10 μA	-	50	-	V
Noise Equivalent Power	V _R = 5V@ λ=950nm	-	8.6x10 ⁻¹⁴	-	W/√Hz
Response Time**	RL = 50Ω, V _R = 0V	-	190	-	nS
	RL = 50Ω, V _R = 10V	-	13	-	

**Response time of 10% to 90% is specified at 660nm wavelength light.

TYPICAL PERFORMANCE

SPECTRAL RESPONSE



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